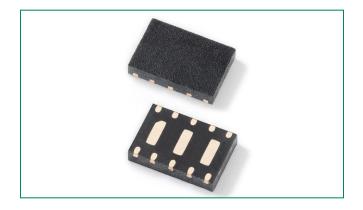
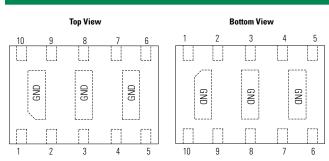


SP2555NUTG 2.5V 45A Diode Array



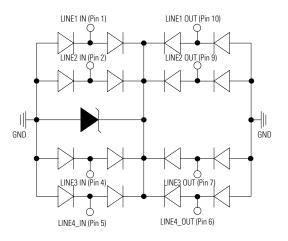


Pinout



NOTE: PIN3, PIN8 are same potential with GND

Functional Block Diagram



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Description

The SP2555NUTG is a low-capacitance, TVS Diode Array designed to provide protection against ESD (electrostatic discharge), CDE (cable discharge events), EFT (electrical fast transients), and lightning induced surges for highspeed, differential data lines. It's packaged in a µDFN package (3.0 x 2.0mm) and each component can protect up 4 channels or 2 differential pairs, up to 45A (IEC 61000-4-5 2nd edition,) and up to 30kV ESD (IEC 61000-4-2). The "flow-through" design minimizes signal distortion, reduces voltage overshoot, and provides a simplified PCB design.

The SP2555NUTG with its low capacitance and low clamping voltage makes it ideal for high-speed data interfaces such as 1GbE applications found in notebooks, switches, etc.

Features

- ESD, IEC 61000-4-2, ±30kV contact, ±30kV air
- EFT, IEC 61000-4-4, 40A (5/50ns)
- Lightning, 45A (8/20µs as defined in IEC 61000-4-5 2nd Edition)
- Low capacitance of 2.5pF@0V (TYP) per I/O
- Low leakage current of 0.1µA (TYP) at 2.5V
- µDFN-10 package is optimized for high-speed data line routing
- · Provides protection for two differential data pairs (4 channels) up to 45A
- · Low operating and clamping voltage
- AEC-Q101 gualified
- Halogen free, Lead free and RoHS compliant

Applications

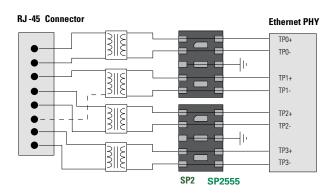
Notebooks

•10/100/1000 Ethernet

Desktops, Servers and

- LVDS Interfaces WAN/LAN Equipment
 - Integrated Magnetics
 - Smart TV

Application Example





Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I _{PP}	Peak Current (t _p =8/20µs)	45	A
P _{pk}	Peak Pulse Power (t _p =8/20µs)	1000	W
T _{op}	Operating Temperature	-40 to 125	°C
T _{STOR}	Storage Temperature	-55 to 150	°C

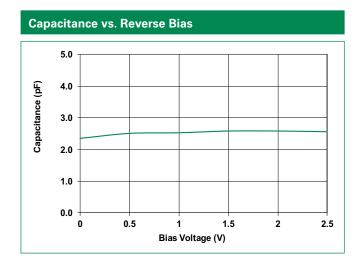
CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the component. This is a stress only rating and operation of the component at these or any other conditions above those indicated in the operational sections of this specification is not implied.

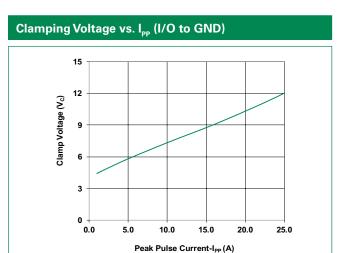
Electrical Characteristics (Top=25°C)

Parameter Symbol Test Conditions		Test Conditions	Min	Тур	yp Max		
Reverse Standoff Voltage	off Voltage V_{RVVM} $I_R \le 1\mu A$				2.5	V	
Reverse Leakage Current	I _R	$V_{RWM} = 2.5V, T = 25^{\circ}C$		0.1	0.5	μA	
Snap Back Voltage	V _{SB}	I _{sb} = 50mA	2.0			V	
Clamp Voltage		$I_{_{\rm PP}}$ = 1A, $t_{_{\rm p}}$ = 8/20µs, Any I/O to Ground		4.5			
		$I_{pp} = 10A$, $t_p = 8/20\mu s$, Any I/O to Ground		7.5			
	V _c	$I_{pp} = 25A$, $t_p = 8/20\mu s$, Any I/O to Ground		12		V	
		$I_{pp} = 45A$, $t_p = 8/20\mu$ s, Line-to-Line ¹ , two I/O Pins connected together on each line		19			
Dynamic Resistance ²	R _{DYN}	TLP, t_p =100ns, Any I/O to Ground		0.1		Ω	
ESD Withstand Voltage	V	IEC 61000-4-2 (Contact)	±30			kV	
	V _{ESD}	IEC 61000-4-2 (Air)	±30			kV	
Diode Capacitance	C _{I/O to GND}	Between I/O Pins and Ground V_ = 0V, f = 1MHz Between I/O Pins		2.5		pF	
	C _{I/O to I/O}	Betweén I/O Pins V _e = 0V, f = 1MHz		1.2		pF	

Notes:

Rating with 2 pins connected together per sugguested diagram (For example, pin1 is connected to pin 10, pin 2 is connected to Pin 9, Pin 4 is connected to pin 7 and pin 5 is connected to pin 6)
Transmission Line Pulse (TLP) with 100ns width, 2ns rise time, and average window t1=70ns to t2= 90ns





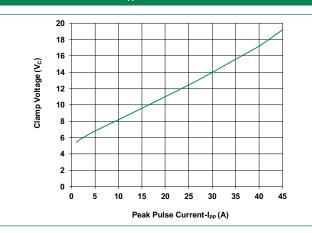
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Revised: 09/11/19

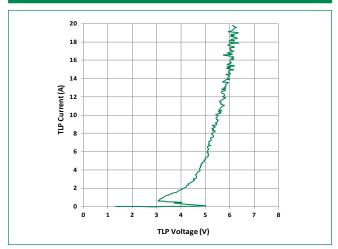


TVS Diode Array (SPA®Diodes) Lightnign Surge Protection - SP2555NUTG

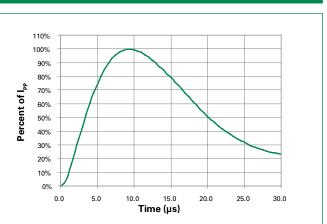
Clamping Voltage vs. I_{pp} (Line-to-Line)



Transmission Line Pulsing(TLP) Plot



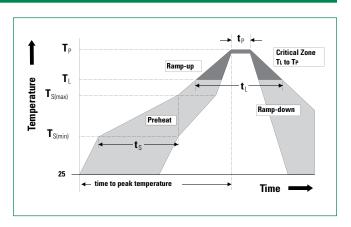
8/20µs Pulse Waveform





Soldering Parameters

Reflow Con	Pb – Free assembly		
Pre Heat	- Temperature Min (T _{s(min)})	150°C	
	- Temperature Max (T _{s(max)})	200°C	
	- Time (min to max) (t _s)	60 – 180 secs	
Average ran	np up rate (Liquidus) Temp (T_L) to peak	3°C/second max	
T _{S(max)} to T _L -	3°C/second max		
Reflow	- Temperature (T _L) (Liquidus)	217°C	
	- Temperature (t _L)	60 – 150 seconds	
Peak Tempe	260 ^{+0/-5} °C		
Time within	20 – 40 seconds		
Ramp-dowr	6°C/second max		
Time 25°C t	8 minutes Max.		
Do not exce	260°C		



SP2555

Ordering Information

Part Numbering System

TVS Diode Arrays (SPA[®] Diodes)

Series

Part Number	Package	Min. Order Qty.
SP2555NUTG	µDFN-10 (3.0x2.0mm)	3000

SP 2555N <u>U</u> T G

Package

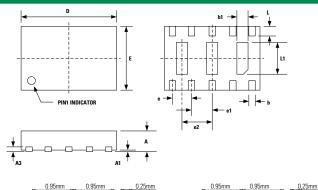
Part Marking System

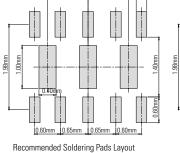






Package Dimensions – µDFN-10 (3.0x2.0mm)





		φ	$ \Psi $	Ψ	φ	Ψ.	
1.98mm	0.85mm	-				-	1.40mm
		<u>0.60</u> r	nm 0.65	mm 0.65n	nm 0.60n		0.60mm
				tencil Ape ncil thickn		ls	

Ø

Package	μDFN-10 (3.0x2.0mm)					
JEDEC	MO-229					
Cumbal	Millimeters			Inches		
Symbol	Min	Nom	Max	Min	Nom	Мах
Α	0.50	0.60	0.65	0.020	0.024	0.026
A1	0.00	0.03	0.05	0.000	0.001	0.002
A3		0.15 Ref		0.006 Ref		
b	0.15	0.20	0.25	0.006	0.008	0.010
b1	0.25	0.35	0.45	0.010	0.014	0.018
D	2.90	3.00	3.10	0.114	0.118	0.122
E	1.90	2.00	2.10	0.075	0.079	0.083
е	0.60 BSC			0	.024 BSC	
e1	0.65 BSC			0	.026 BSC	
e2	0.95 BSC				0.037	
L	0.25	0.30	0.35	0.010	0.012	0.014
L1	0.95	1.00	1.05	0.037	0.039	0.041

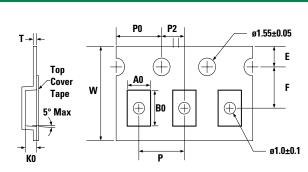
Notes :

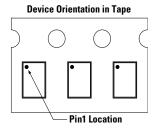
Ŕ Ø

1. All dimensions are in millimeters

Dimensions include solder plating.
Dimensions are exclusive of mold flash & metal burr

Tape & Reel Specification - µDFN-10 (3.0x2.0mm)





Package	μDFN-10 (3.0x2.0mm)		
Symbol	Millimeters		
A0	2.30 +/- 0.10		
B0	3.20 +/- 0.10		
E	1.75 +/- 0.10		
F	3.50 +/- 0.05		
КО	1.0 +/- 0.10		
Р	4.00 +/- 0.10		
PO	4.00 +/- 0.10		
P2	2.00 +/- 0.10		
Т	0.3 +/- 0.05		
W	8.00 +0.30/- 0.10		

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